

SUR552J

Epitaxial planar NPN/PNP silicon transistor

Description

• Dual chip digital transistor

Features

- Both SRC1204 chips and SRA2204 chip in SOT-363 package
- Simplify circuit design
- Reduce a quantity of parts and manufacturing process

Package: SOT-363

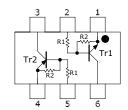
Ordering Information

Type NO.	Marking	Package Code	
SUR552J	52J□	SOT-363	

□ : Year & Week Code

Equivalent circuit & PIN Connections

• Equivalent Circuit



	\mathbf{R}_{1}	\mathbf{R}_2
Tr1	47ΚΩ	47ΚΩ
Tr2	47ΚΩ	47ΚΩ

PIN Connections

- 1. COMMON 1
- 2. IN 1
- 3. OUT 2
- 4. COMMON 2
- 5. IN 2
- 6. OUT 1

Absolute Maximum Rai lgs [Tr1, Tr2]

 $(Ta=25^{\circ}C)$

Characteristic	Symbol	Rating		Unit	
	Symbol	Tr1	Tr2		
Output voltage	Vo	50	-50	V	
Input voltage	VI	40,-10	-40,10	V	
Output current	I _O	100	-100	mA	
Power dissipation	P _D **	200		mW	
Junction temperature	Tı	150		°C	
Storage temperature Range	T_{stg}	-55 ~ 150		°C	

*: Total rating

KSD-R5S019-001

Electrical Characteristics [Tr1]

 $(Ta=25^{\circ}C)$

Characteristic	Symbol	Symbol Test Condition		Тур.	Max.	Unit
Output cut-off current	I _{O(OFF)}	V ₀ =50V, V _I =0	-	-	500	nA
DC current gain	G_{I}	V _O =5V, I _O =10mA	80	200	-	ı
Output voltage	V _{O(ON)}	I_O =10mA, I_I =0.5mA	-	0.1	0.3	V
Input voltage (ON)	$V_{I(ON)}$	V ₀ =0.2V, I ₀ =5mA	-	2.8	5.0	>
Input voltage (OFF)	V _{I(OFF)}	V _O =5V, I _O =0.1mA	1.0	1.2	-	٧
Transition frequency	f_T^*	V_0 =10V, I_0 =5mA, f=1MHz	-	200	-	MHz
Input current	I _I	V_I =5V, I_O =0	-	-	0.18	mA
Input resistor (Input to base)	R_1	-	33	47	61	ΚΩ
Input resistor (Base to common)	R ₂	-	33	47	61	K Ω

^{* :} Characteristic of transistor only

Electrical Characteristics [Tr2]

 $(Ta=25^{\circ}C)$

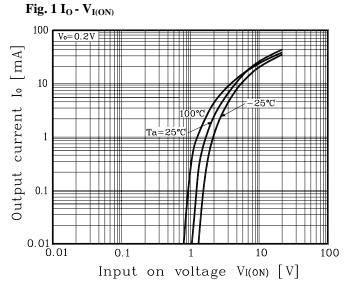
Characteristic	Symbol	Symbol Test Condition		Тур.	Max.	Unit
Output cut-off current	I _{O(OFF)}	V _O =-50V, V _I =0	-	1	-500	nA
DC current gain	G_{I}	V _O =-5V, I _O =-10mA	80	200	-	-
Output voltage	V _{O(ON)}	I _O =-10mA, I _I =-0.5mA	-	-0.1	-0.3	V
Input voltage (ON)	$V_{I(ON)}$	V _O =-0.2V, I _O =-5mA	-	-2.8	-5.0	V
Input voltage (OFF)	V _{I(OFF)}	V _O =-5V, I _O =-0.1mA	-1.0	-1.2	-	V
Transition frequency	f_T^*	V _O =-10V, I _O =-5mA, f=1MHz	-	200	-	MHz
Input current	I_{I}	V _I =-5V, I _O =0	-	1	-0.18	mA
Input resistor (Input to base)	R ₁	-	33	47	61	K Ω
Input resistor (Base to common)	R ₂	-	33	47	61	K Ω

^{* :} Characteristic of transistor only

KSD-R5S019-001 2

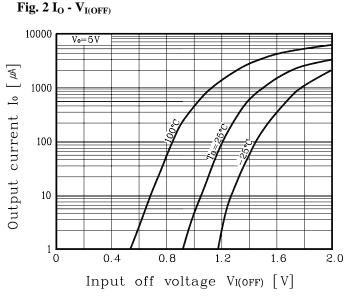
Electrical Characteristic Curves

[Tr1]



[Tr2]

Fig. 2 I_O - $V_{I(OFF)}$



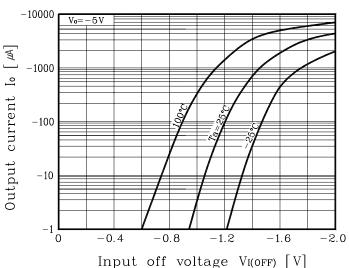


Fig. 3 G_I- I_O

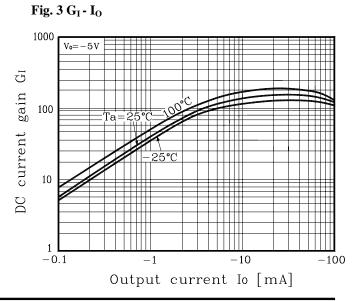
1000

Vo=5V

Ta=25°C

Ta=25°C

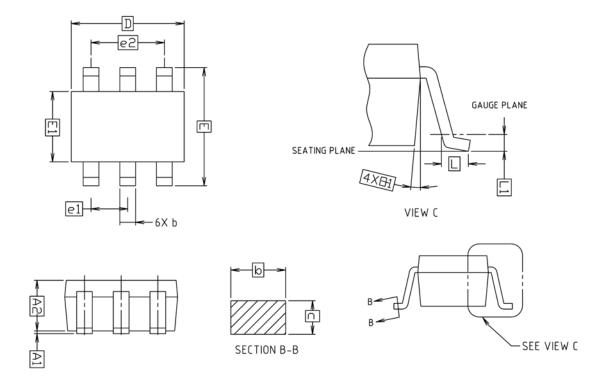
Output current Io [mA]



KSD-R5S019-001

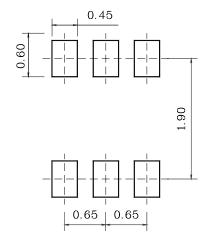
3

Outline Dimension



		MILLIMETERS				
SYMBOL	MINIMUM	NOMINAL	MAXIMUM	NOTE		
A1	0.00	_	0.10			
A2	0.90	0.95	1.00			
b	0.25	_	0.40			
С	0.10	_ 0.25				
D	1.90	2.00	2.10			
Ε	1.95	2.10 2.25				
E1	1.15 1.25 1.35					
e1						
e2						
L	0.25	5				
L1						

* Recommend PCB solder land [Unit: mm]



KSD-R5S019-001

4

The AUK Corp. products are intended for the use as components in general electronic equipment (Office and communication equipment, measuring equipment, home appliance, etc.).

Please make sure that you consult with us before you use these AUK Corp. products in equipments which require high quality and / or reliability, and in equipments which could have major impact to the welfare of human life(atomic energy control, airplane, spaceship, transportation, combustion control, all types of safety device, etc.). AUK Corp. cannot accept liability to any damage which may occur in case these AUK Corp. products were used in the mentioned equipments without prior consultation with AUK Corp..

Specifications mentioned in this publication are subject to change without notice.

KSD-R5S019-001 5